



**THE DATASHEET OF
CM1215-04SO**



CM1215

1, 2 and 4-Channel Low Capacitance ESD Arrays

Product Description

The CM1215 family of diode arrays provides ESD protection for electronic components or sub-systems requiring minimal capacitive loading. These devices are ideal for protecting systems with high data and clock rates or for circuits requiring low capacitive loading. Each ESD channel consists of a pair of diodes in series which steer the positive or negative ESD current pulse to either the positive (VP) or negative (VN) supply rail. The CM1215 protects against ESD pulses up to ± 15 kV per the IEC 61000-4-2 standard.

This device is particularly well-suited for protecting systems using high-speed ports such as USB2.0, IEEE1394 (Firewire[®], iLink[™]), Serial ATA, DVI, HDMI and corresponding ports in removable storage, digital camcorders, DVD-RW drives and other applications where extremely low loading capacitance with ESD protection are required in a small package footprint.

Features

- One, two, and four channels of ESD Protection
- Provides ± 15 kV ESD Protection on Each Channel Per the IEC 61000-4-2 ESD Requirements
- Channel Loading Capacitance of 1.6 pF Typical
- Channel I/O to GND Capacitance Difference of 0.04 pF Typical
- Mutual Capacitance of 0.13 pF Typical
- Minimal Capacitance Change with Temperature and Voltage
- Each I/O Pin Can Withstand Over 1000 ESD Strikes
- SOT Packages
- These Devices are Pb-Free and are RoHS Compliant

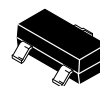
Applications

- IEEE1394 Firewire[®] Ports at 400 Mbps / 800 Mbps
- DVI Ports, HDMI Ports in Notebooks, Set Top Boxes, Digital TVs, LCD Displays
- Serial ATA Ports in Desktop PCs and Hard Disk Drives
- PCI Express Ports
- General Purpose High-Speed Data Line ESD Protection



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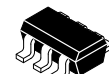
**SOT23-3
SO SUFFIX
CASE 419AH**



**SOT143
SR SUFFIX
CASE 527AF**

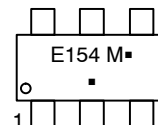
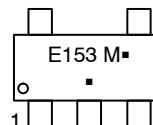
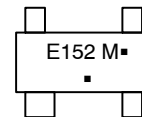
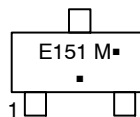


**SOT23-5
SO SUFFIX
CASE 527AH**



**SOT23-6
SO SUFFIX
CASE 527AJ**

MARKING DIAGRAM



XXXX = Specific Device Code
 M = Date Code
 ■ = Pb-Free Package
 (Note: Microdot may be in either location)

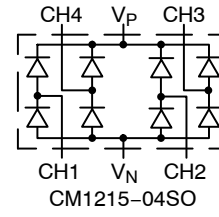
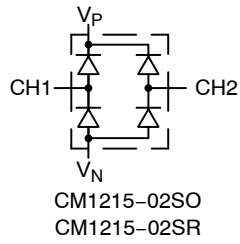
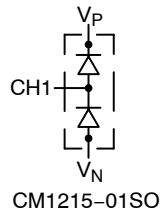
ORDERING INFORMATION

Device	Package	Shipping [†]
CM1215-01SO	SOT23-3 (Pb-Free)	3000/Tape & Reel
CM1215-02SR	SOT143 (Pb-Free)	3000/Tape & Reel
CM1215-02SO	SOT23-5 (Pb-Free)	3000/Tape & Reel
CM1215-04SO	SOT23-6 (Pb-Free)	3000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

CM1215

BLOCK DIAGRAM



PACKAGE / PINOUT DIAGRAMS

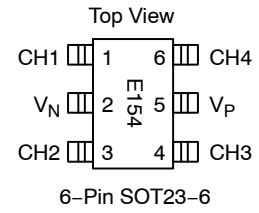
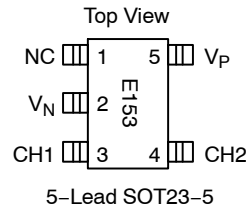
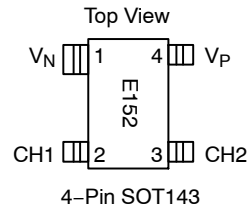
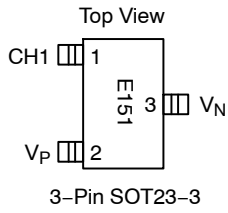


Table 1. PACKAGE PIN DESCRIPTIONS

Pin Name	SOT23-3	SOT143	SOT23-5	SOT23-6	Type	Description
	Pin No.	Pin No.	Pin No.	Pin No.		
CH1	1	2	3	1	I/O	ESD Channel
V _N	3	1	2	2	GND	Negative voltage supply rail
CH2	-	3	4	3	I/O	ESD Channel
CH3	-	-	-	4	I/O	ESD Channel
V _P	2	4	5	5	PWR	Positive voltage supply rail
CH4	-	-	-	6	I/O	ESD Channel
N/C	-	-	1	-	-	No Connection

CM1215

SPECIFICATIONS

Table 2. ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Units
Operating Supply Voltage (V_P-V_N)	6	V
Diode Forward DC Current (Note 1)	20	mA
DC Voltage at any Channel Input	$(V_N-0.5)$ to $(V_P+0.5)$	V
Operating Temperature Range		
Ambient	-40 to +85	°C
Junction	-40 to +125	°C
Storage Temperature Range	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 3. STANDARD OPERATING CONDITIONS

Parameter	Rating	Units
Operating Temperature Range	-40 to +85	°C
Package Power Rating		mW
SOT23-3 Package (CM1215-01SO)	225	
SOT143 Package (CM1215-02SR)	225	
SOT23-5 Package (CM1215-02SO)	225	
SOT23-6 Package (CM1215-04SO)	225	

Table 4. ELECTRICAL OPERATING CHARACTERISTICS (Note 1)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_P	Operating Supply Voltage (V_P-V_N)			3.3	5.5	V
I_P	Operating Supply Current	$(V_P-V_N) = 3.3$ V			8	μA
V_F	Diode Forward Voltage Top Diode Bottom Diode	$I_F = 20$ mA; $T_A = 25^\circ\text{C}$	0.6 0.6	0.8 0.8	0.95 0.95	V
I_{LEAK}	Channel Leakage Current	$T_A = 25^\circ\text{C}$; $V_P = 5$ V, $V_N = 0$ V		±0.1	±1.0	μA
C_{IN}	Channel Input Capacitance	At 1 MHz, $V_P = 3.3$ V, $V_N = 0$ V, $V_{IN} = 1.65$ V;		1.6	2.0	pF
ΔC_{IN}	Channel I/O to GND Capacitance Difference			0.04		pF
C_{MUTUAL}	Mutual Capacitance	$(V_P-V_N) = 3.3$ V		0.13		pF
V_{ESD}	ESD Protection Peak Discharge Voltage at any channel input, in system, contact discharge per IEC 61000-4-2 standard	$T_A = 25^\circ\text{C}$ (Notes 2 and 3)	±15			kV
V_{CL}	Channel Clamp Voltage Positive Transients Negative Transients	$I_{PP} = 1$ A, $t_P = 8/20$ μS; $T_A = 25^\circ\text{C}$;		$V_P+1.5$ $V_N-1.5$		V
R_{DYN}	Dynamic Resistance Positive transients Negative transients	$I_{PP} = 1$ A, $t_P = 8/20$ μS; $T_A = 25^\circ\text{C}$;		0.4 0.4		Ω

- All parameters specified at $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ unless otherwise noted.
- Standard IEC 61000-4-2 with $C_{Discharge} = 150$ pF, $R_{Discharge} = 330$ Ω, $V_P = 3.3$ V, V_N grounded.
- From I/O pins to V_P or V_N only. V_P bypassed to V_N with low ESR 0.2 μF ceramic capacitor.

PERFORMANCE INFORMATION

Input Channel Capacitance Performance Curves

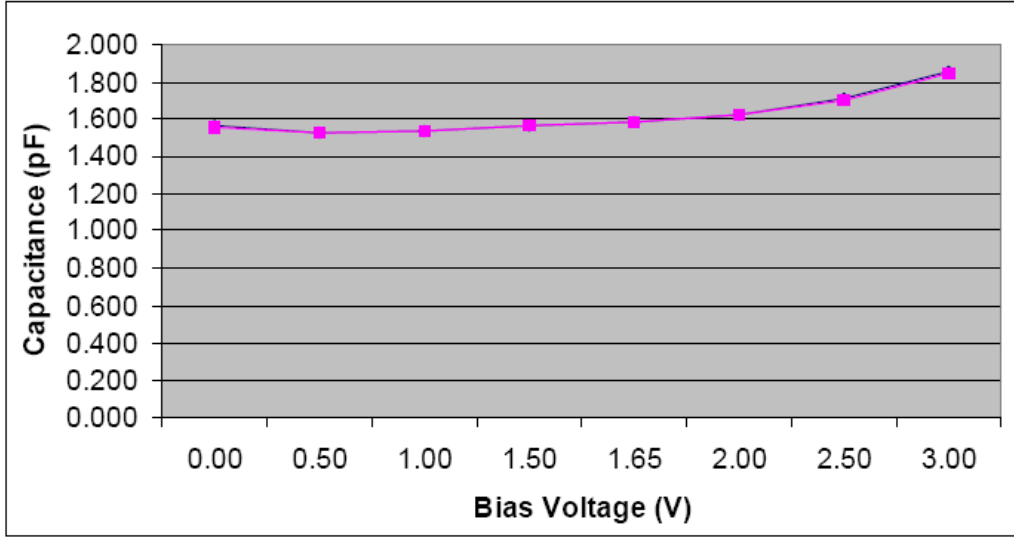


Figure 1. Typical Variation of C_{IN} vs. V_{IN}
 (f = 1 MHz, V_P = 3.3 V, V_N = 0 V, 0.1 μ F Chip Capacitor between V_P and V_N , T_A = 25°C)

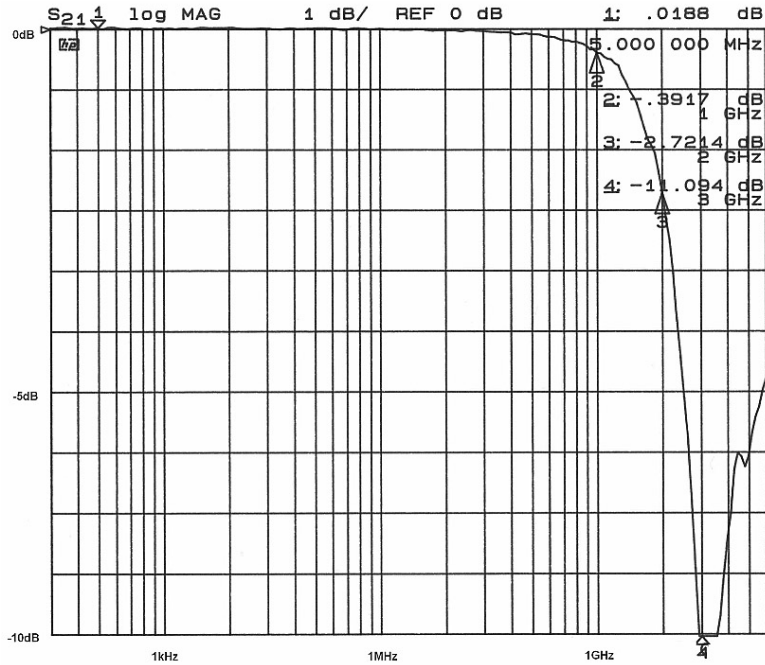


Figure 2. Typical Filter Performance (Nominal Conditions unless Specified Otherwise, 50 Ohm Environment)

APPLICATION INFORMATION

Design Considerations

In order to realize the maximum protection against ESD pulses, care must be taken in the PCB layout to minimize parasitic series inductances on the Supply/ Ground rails as well as the signal trace segment between the signal input (typically a connector) and the ESD protection device. Refer to Figure 1, which illustrates an example of a positive ESD pulse striking an input channel. The parasitic series inductance back to the power supply is represented by L1 and L2. The voltage VCL on the line being protected is:

$$V_{CL} = \text{Fwd voltage drop of } D_1 + V_{SUPPLY} + L_1 \times d(I_{ESD}) / dt + L_2 \times d(I_{ESD}) / dt$$

where IESD is the ESD current pulse, and VSUPPLY is the positive supply voltage.

An ESD current pulse can rise from zero to its peak value in a very short time. As an example, a level 4 contact discharge per the IEC61000-4-2 standard results in a current pulse that rises from zero to 30 Amps in 1ns. Here d(IESD)/dt can be approximated by d(ESD)/dt, or 30/(1x10-9). So just 10 nH of series inductance (L1 and L2 combined) will lead to a 300 V increment in VCL!

Similarly for negative ESD pulses, parasitic series inductance from the VN pin to the ground rail will lead to drastically increased negative voltage on the line being protected.

As a general rule, the ESD Protection Array should be located as close as possible to the point of entry of expected electrostatic discharges. The power supply bypass capacitor mentioned above should be as close to the VP pin of the Protection Array as possible, with minimum PCB trace lengths to the power supply, ground planes and between the signal input and the ESD device to minimize stray series inductance.

Additional Information

See also ON Semiconductor Application Note, “Design Considerations for ESD Protection”, in the Applications section.

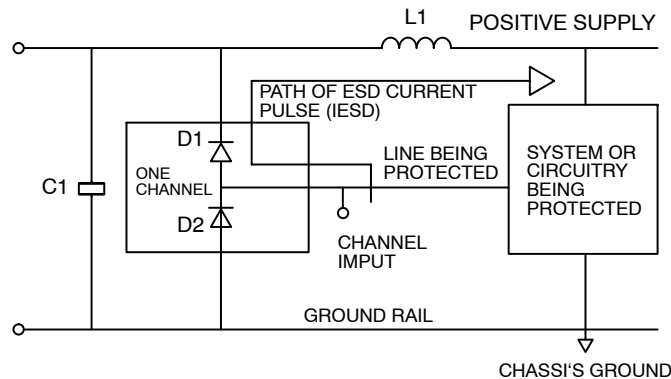
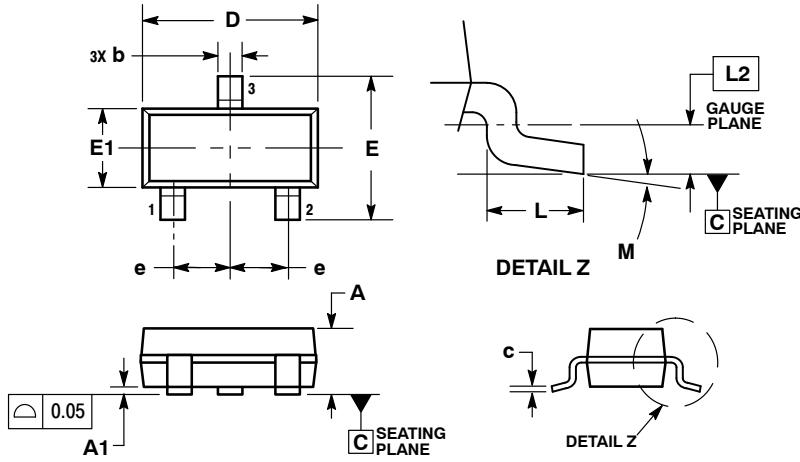


Figure 3. Application of Positive ESD Pulse between Input Channel and Ground

CM1215

PACKAGE DIMENSIONS

SOT-23 3-Lead (TO-236AA)
CASE 419AH-01
ISSUE O

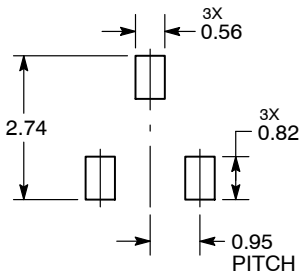


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
5. PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE.

DIM	MILLIMETERS	
	MIN	MAX
A	0.75	1.17
A1	0.05	0.15
b	0.30	0.50
c	0.08	0.20
D	2.80	3.05
E	2.10	2.64
E1	1.20	1.40
e	0.95 BSC	
L	0.40	0.60
L2	0.25 BSC	
M	0°	8°

RECOMMENDED SOLDERING FOOTPRINT*



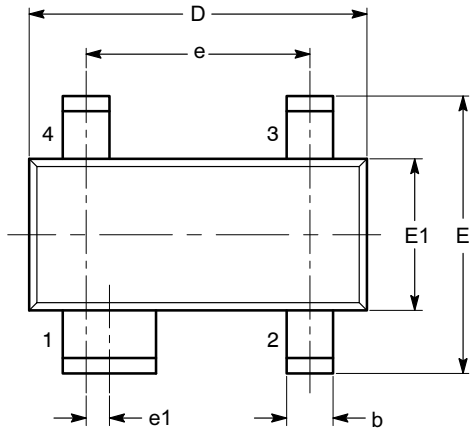
DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

CM1215

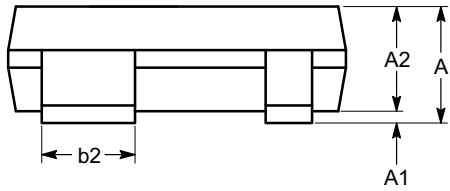
PACKAGE DIMENSIONS

SOT-143, 4 Lead
CASE 527AF-01
ISSUE A

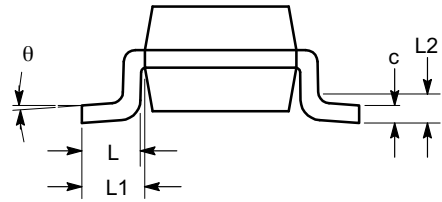


TOP VIEW

SYMBOL	MIN	NOM	MAX
A	0.80		1.22
A1	0.05		0.15
A2	0.75	0.90	1.07
b	0.30		0.50
b2	0.76		0.89
c	0.08		0.20
D	2.80	2.90	3.04
E	2.10		2.64
E1	1.20	1.30	1.40
e	1.92 BSC		
e1	0.20 BSC		
L	0.40	0.50	0.60
L1	0.54 REF		
L2		0.25	
θ	0°		8°



SIDE VIEW



END VIEW

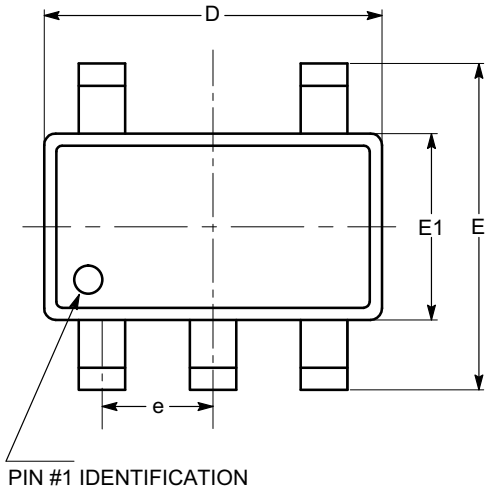
Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC TO-253.

CM1215

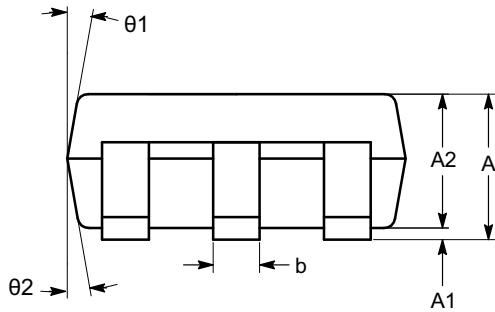
PACKAGE DIMENSIONS

SOT-23, 5 Lead
CASE 527AH-01
ISSUE O

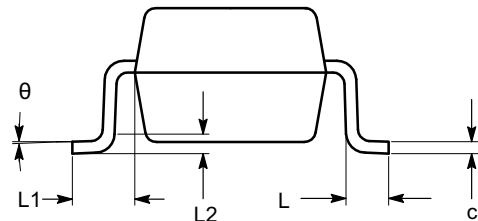


TOP VIEW

SYMBOL	MIN	NOM	MAX
A	0.90		1.45
A1	0.00		0.15
A2	0.90	1.15	1.30
b	0.30		0.50
c	0.08		0.22
D	2.90 BSC		
E	2.80 BSC		
E1	1.60 BSC		
e	0.95 BSC		
L	0.30	0.45	0.60
L1	0.60 REF		
L2	0.25 REF		
θ	0°	4°	8°
$\theta 1$	5°	10°	15°
$\theta 2$	5°	10°	15°



SIDE VIEW



END VIEW

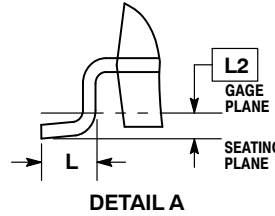
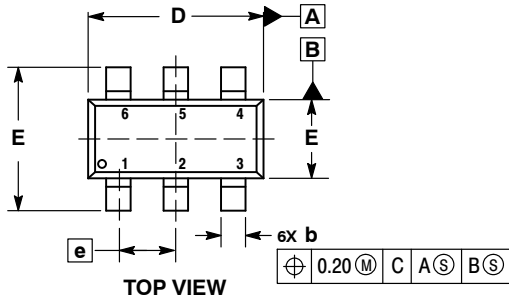
Notes:

- (1) All dimensions in millimeters. Angles in degrees.
- (2) Complies with JEDEC standard MO-178.

CM1215

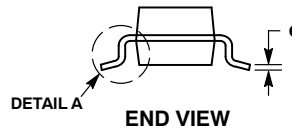
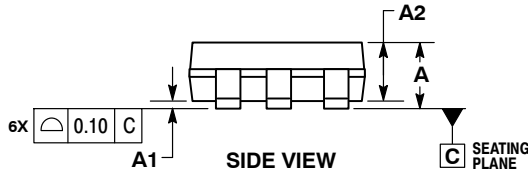
PACKAGE DIMENSIONS

SOT-23, 6 Lead
CASE 527AJ-01
ISSUE A

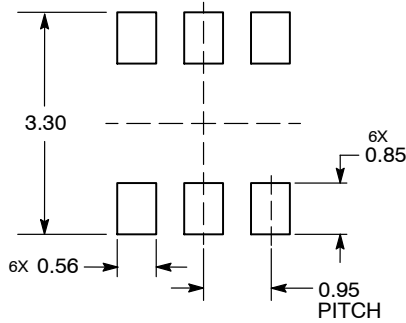


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DATUM C IS THE SEATING PLANE.

MILLIMETERS		
DIM	MIN	MAX
A	---	1.45
A1	0.00	0.15
A2	0.90	1.30
b	0.20	0.50
c	0.08	0.26
D	2.70	3.00
E	2.50	3.10
E1	1.30	1.80
e	0.95 BSC	
L	0.20	0.60
L2	0.25 BSC	



RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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